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MBRD630CT SCHOTTKY RECTIFIER

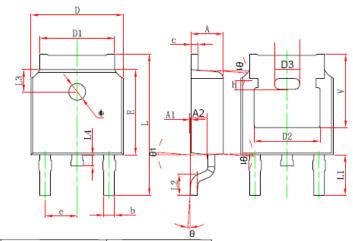
Applications:

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection
- Battery charging

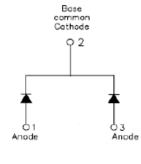
Features:

- Popular DPAK outline
- Small foot print, surface moutable
- Low forward voltage drop
- High frequency operation
- · Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Mechanical Dimensions: In Inches / mm



Symbol	Dimensions In Millimeters		Dimensions In Inches	
Syllibol	Min.	Max.	Min.	Max.
Α	2.200	2.380	0.087	0.094
A1	0.000	0.100	0.000	0.004
b	0.710	0.810	0.028	0.032
С	0.460	0.560	0.018	0.022
D	6.500	6.700	0.256	0.264
D1	5.130	5.460	0.202	0.215
D2	4.830	REF.	0.190	REF.
E	6.000	6.200	0.236	0.244
е	2.186	2.386	0.086	0.094
L	9.800	10.400	0.386	0.409
L1	2.900	REF.	0.114 REF.	
L2	1.400	1.700	0.055	0.067
L3	1.600	REF.	0.063 REF.	
L4	0.600	1.000	0.024	0.039
Φ	1.100	1.300	0.043	0.051
θ	0°	8°	0°	8°
A2	0.910	1.110	0.036	0.044
V	5.350 REF.		0.211	REF.
D3	1.778REF.		0.070	REF.
h	0.762REF.		0.030	REF.
A 1	7°		7	•



DPAK

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Marking Diagram:



Where XXXXX is YYWWL

MBR = Device Type D = Package type

6 = Forward Current (6A) 30 = Reverse Voltage (30V)

CT = Configuration

 SSG
 = SSG

 YY
 = Year

 WW
 = Week

 L
 = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

Ordering Information:

Device	Package	Shipping
MBRD630CT	DPAK (Pb-Free)	2500pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V_{RWM}	-	30	V
Max. Average Forward	I _{F(AV)}	50% duty cycle @T _C =105°C, rectangular wave form	6	А
Max. Peak One Cycle Non- Repetitive Surge Current (per leg)	I _{FSM}	8.3 ms, half Sine pulse	75	А

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Electrical Characteristics:

Characteristics	Symbol	Condition	Max.	Units
	V_{F1}	@ 3 A, Pulse, T _J = 25 °C	0.70	V
Max. Forward Voltage Drop*		@ 6 A, Pulse, T _J = 25 °C	0.90	V
Wax. I of ward voltage brop	V_{F2}	@ 3 A, Pulse, T _J = 125 °C	0.65	V
		@ 6 A, Pulse, T _J = 125 °C	0.85	
Max. Reverse Current (per	I _{R1}	$@V_R = rated V_R$	0.1	mA
leg) *		T _C = 25 °C		
	I _{R2}	$@V_R = rated V_R$	15	mA
	'R2	T _C = 125 °C	10	
Max. Voltage Rate of Change	dv/dt	-	10,000	V/μs

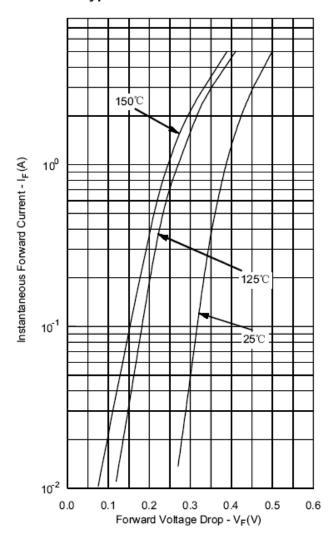
^{*} Pulse Width < 300 μ s, Duty Cycle <2%

Thermal-Mechanical Specifications:

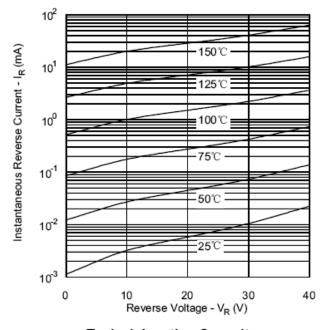
Characteristics	Symbol	Condition	Specification	Units
Junction Temperature Range	T _J	-	-55 to +150	°C
Storage Temperature Range	T _{stg}	-	-55 to +150	°C
Maximum Thermal Resistance Junction to Case	$R_{\theta JC}$	DC operation	6	°C/W
Maximum Thermal Resistance Junction to Ambient	$R_{\theta JA}$	-	80	°C/W
Approximate Weight	wt	-	0.39	g
Case Style		DPAK	_	·

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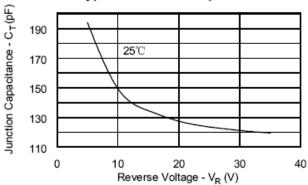
Typical Forward Characteristics



Typical Reverse Characteristics



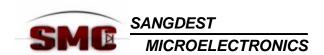
Typical Junction Capacitance



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